

# YJ Planar Schottky Barrier Diode Die Specification

100V 100A, 250mil, Schottky barrier diode die based on silicon planar process  
Part No.: PSB250H100AS-290A

## Main Products Characteristics

### Maximum Ratings

### Static Electrical Characteristics (Ta = 25°C)

$I_F = 100 \text{ A}$

2%

### Device Schematics and Outline Drawing

Die Thickness \*